

MGBR20V60

Preliminary

MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC **MGBR20V60** is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high current capability, etc.

The UTC **MGBR20V60** suitable for free wheeling, high frequency inverters, polarity protection, and low voltage.

FEATURES

- * Very low forward voltage drop
- * High current capability
- * High surge capability
- * High efficiency

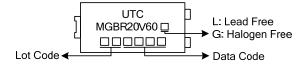
SYMBOL

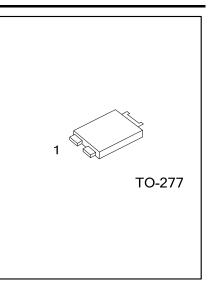
ORDERING INFORMATION

Ordering Number		Deskere	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR20V60L-T27-R	MGBR20V60G-T27-R	TO-277	А	К	А	Tape Reel	
Note: Pin Assignment: A: Anode K: Common Cathode							

Note. Fill Assignment. A. Anoue K. Common Calno	ue
MGBR20V60L-T27-R (1)Packing Type	(1) R: Tape Reel
(2)Package Type	(2) T27: TO-227
(3)Lead Free	(3) L: Lead Free, G: Halogen Free

MARKING





Preliminary

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage (Note 1)	V_{RM}	60	V
Working Peak Reverse Voltage	V _{RWM}	60	V
Peak Repetitive Reverse Voltage	V _{RRM}	60	V
Average Rectified Output Current T _C =125°C	lo	20	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	250	А
Operating Junction Temperature	TJ	-65~+150	°C
Storage Temperature	T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	73	°C/W	
Junction to Case	θ _{JC}	13	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	60			V
Forward Voltage Drop		I _F =20A, T _C =25°C			0.60	V
		I _F =20A, T _C =125°C			0.55	V
Peak Reverse Current at Rated DC	DM	V _R =60V, T _C =25°C			500	μA
Blocking Voltage (Note 1)		V _R =60V, T _C =125°C			50	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.

3. Mounted on an FR4 PCB, single-sided copper, with 100cm² copper pad area.



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